

HIGH PERFORMANCE SILVER POLYMER PASTES FOR SHJ CELLS

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OUTLINE

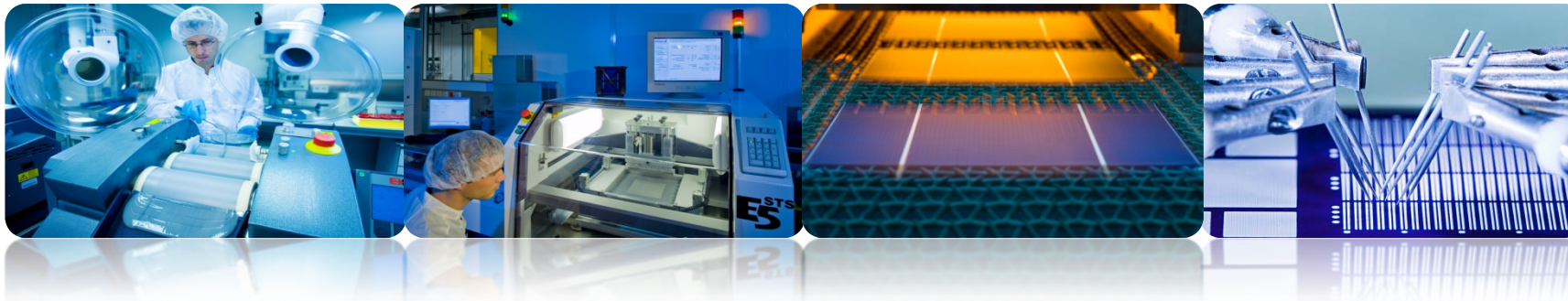
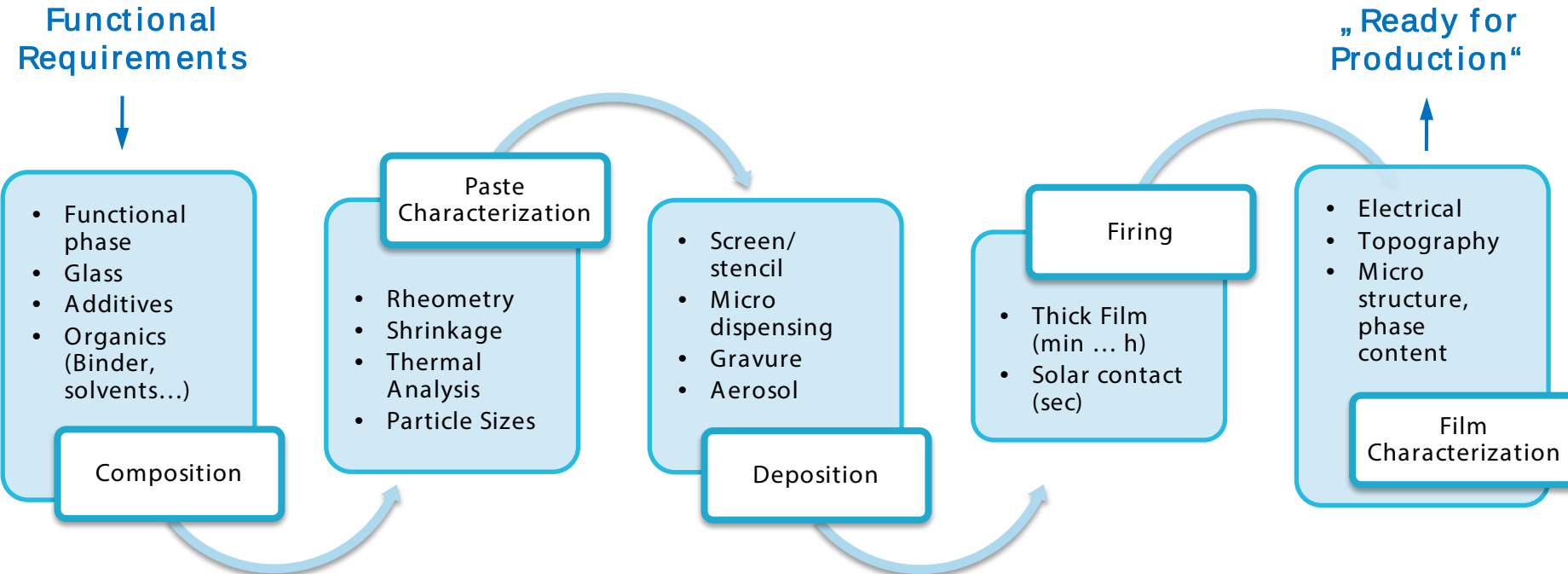
- IKTS: Paste Research Service (PRS) and Paste Vendor for Niche Markets (PVN)
- SHJ: Low Temperature Pastes
- Silver polymer paste
 - Experimental
 - Results and discussion
- Summary

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IKTS Group Thick Film Technology, Photovoltaics: Paste Research Service PRS

Paste Development, Manufacturing and Characterization



Paste Vendor for Niche Markets PVN: example AlN substrates



Paste	Metal	R/ mOhm/sq	Application
FK 1205	AgPd	< 25	R termination
FK 1220	AgPd	< 25	Acid stable
FK 1164	AgPd	< 25	Via paste
FK 1071	AgPt	< 6	Low resistance
FK 1282	AgPt	< 35	Dealloy stable

Paste	Cond. Phase	R/ Ohm/sq	TCR/ ppm/K
FK 9821m	AgPd	0.1	± 100
FK 9831m	AgPd	1	± 100
FK9611	RuO ₂	10	± 100
FK9615	RuO ₂	50	± 100
FK9621	RuO ₂	100	± 100
FK9631	RuO ₂	1000	± 100

Future of crystalline silicon solar cell

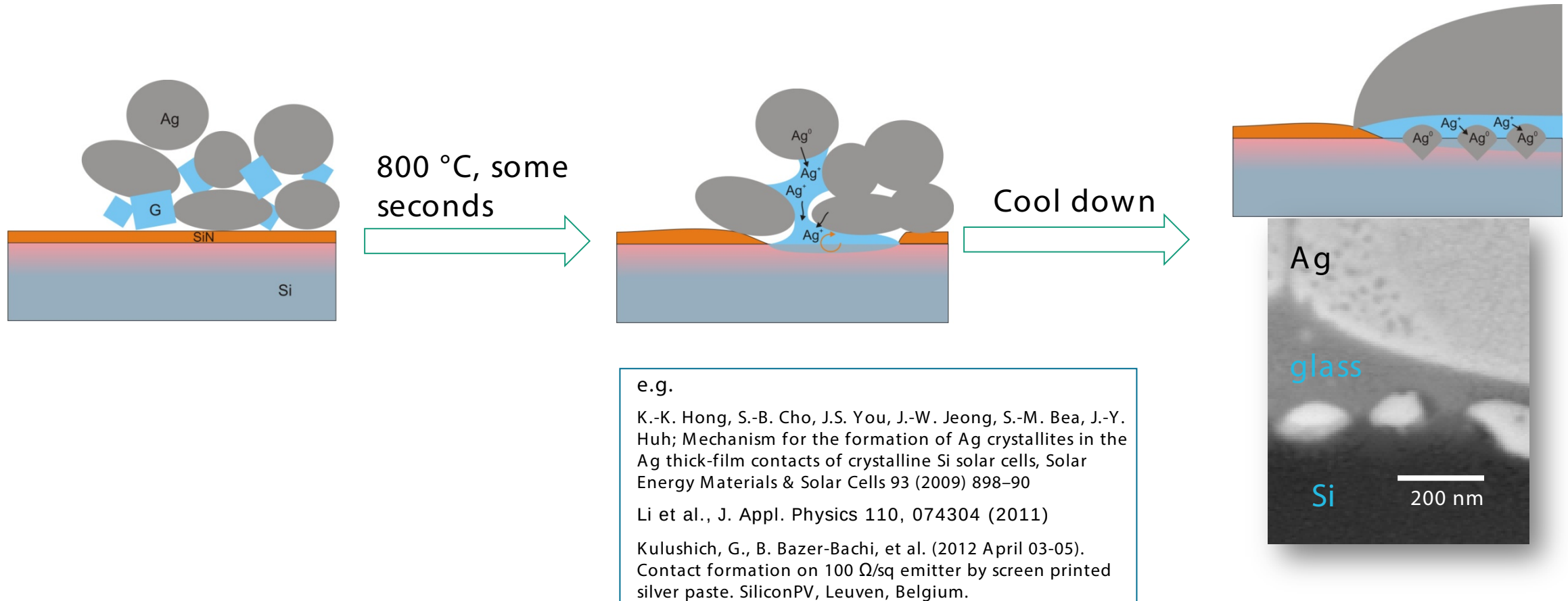


- ITRPV roadmap 2015 predicts efficiencies for SHJ up to 25 % and market share of 10 % in the year 2025

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Conventional pastes for front side metallization



SHJ cell concept



silver

ITO

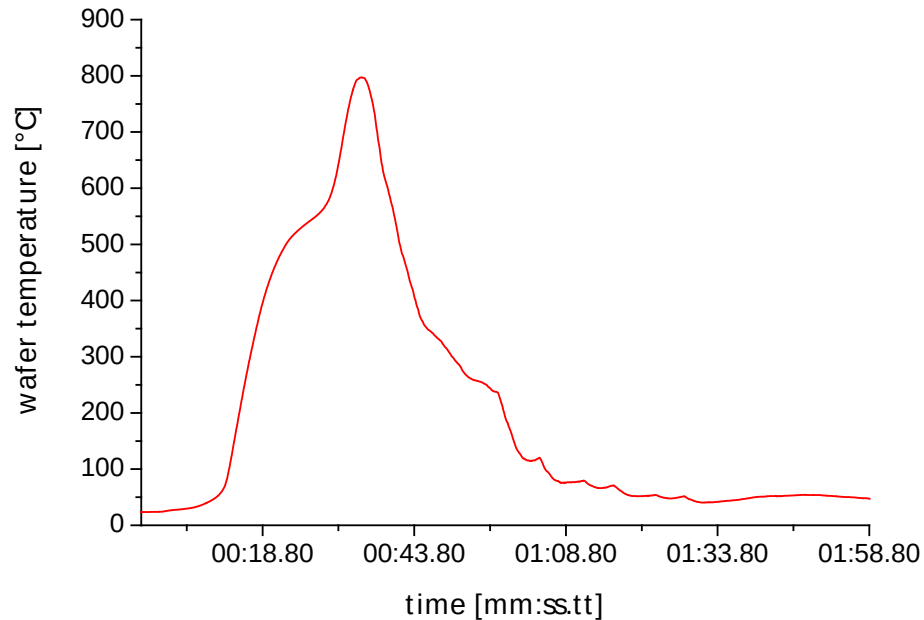
emitter: a-Si (p)

passivation: a-Si (i)

base: c-Si (n)

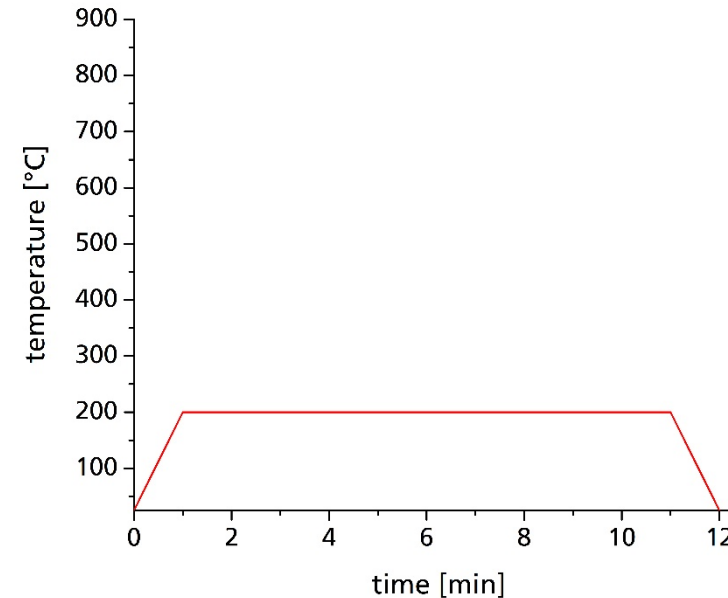
Maximum process
temperature $\leq 200^{\circ}\text{C}$

Low temperature thick film pastes for solar cell metallization



Conductive phase Ag

glass → crucial for adhesion, reactive contact formation, and interface/finger conductivity



Conductive phase Ag or LMPA

polymer → crucial for adhesion and interface/finger conductivity

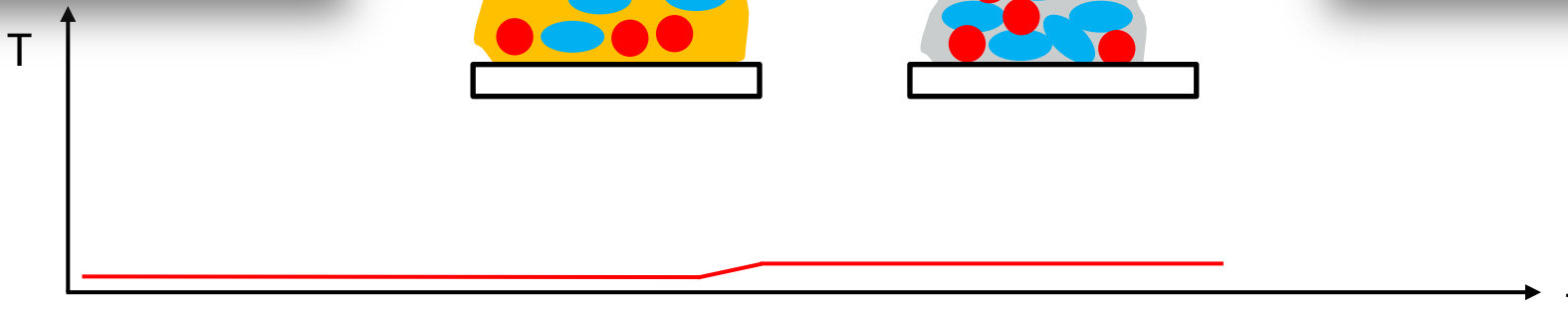
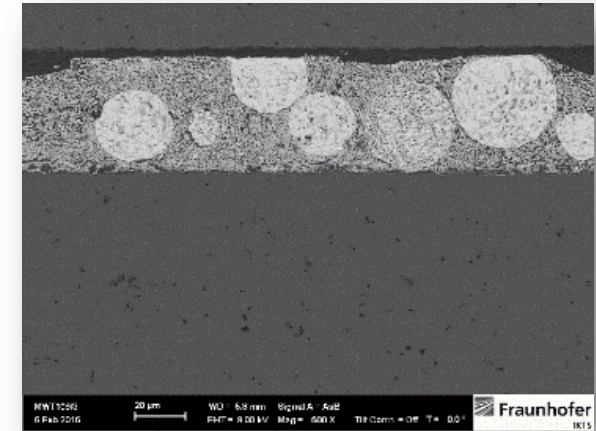
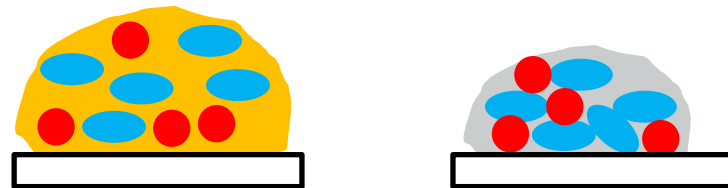
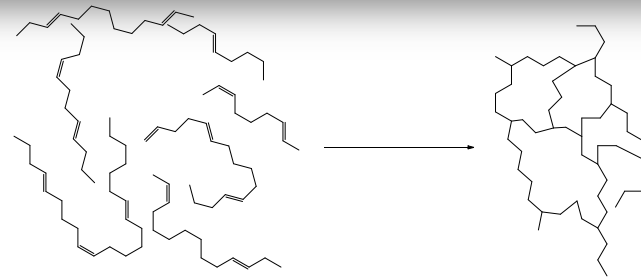
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Processing of low temperature pastes



Thermal (IR or convection; air or nitrogen, 2400 wafers / h, manufactured 2015 by REHM, Germany)



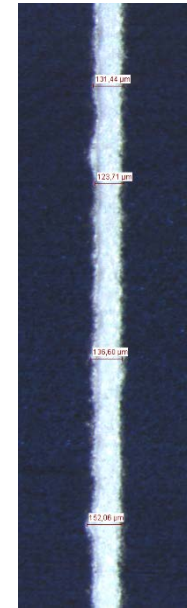
Low temperature thick film pastes for solar cell metallization



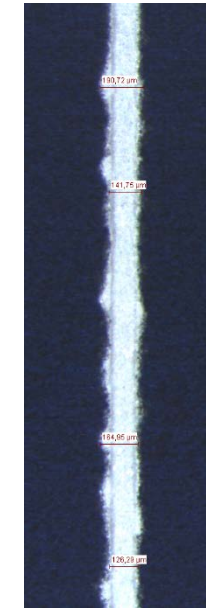
40 μm



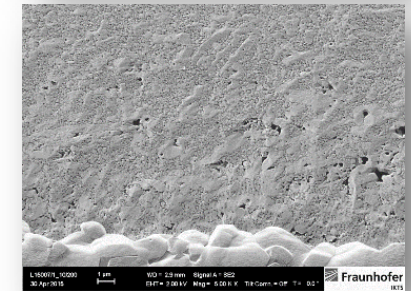
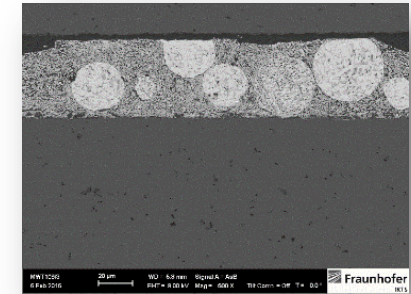
60 μm



80 μm



100 μm



- tuning of curable binder: polymer, solvent

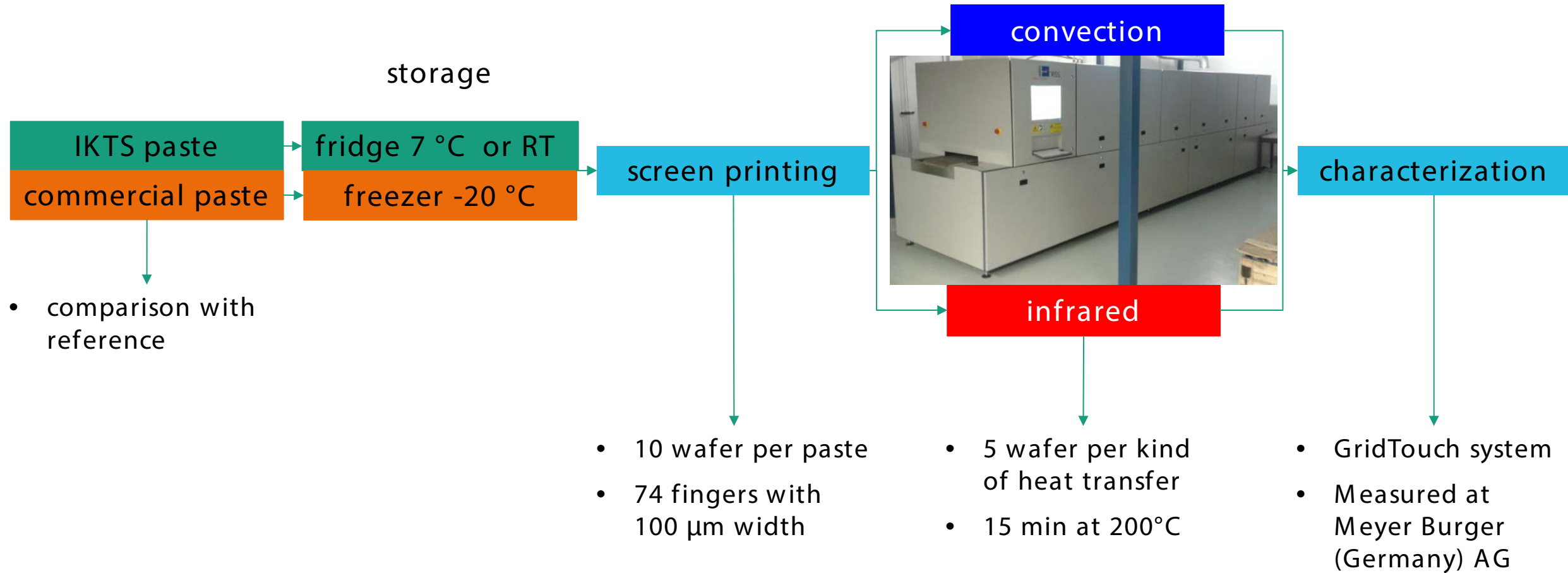


$$R_{sq} = 25 \text{ m}\Omega/\text{sq}$$



- conductive phases:
Ag mono/polymodal
Low Melting Point
Alloys (LMPA)

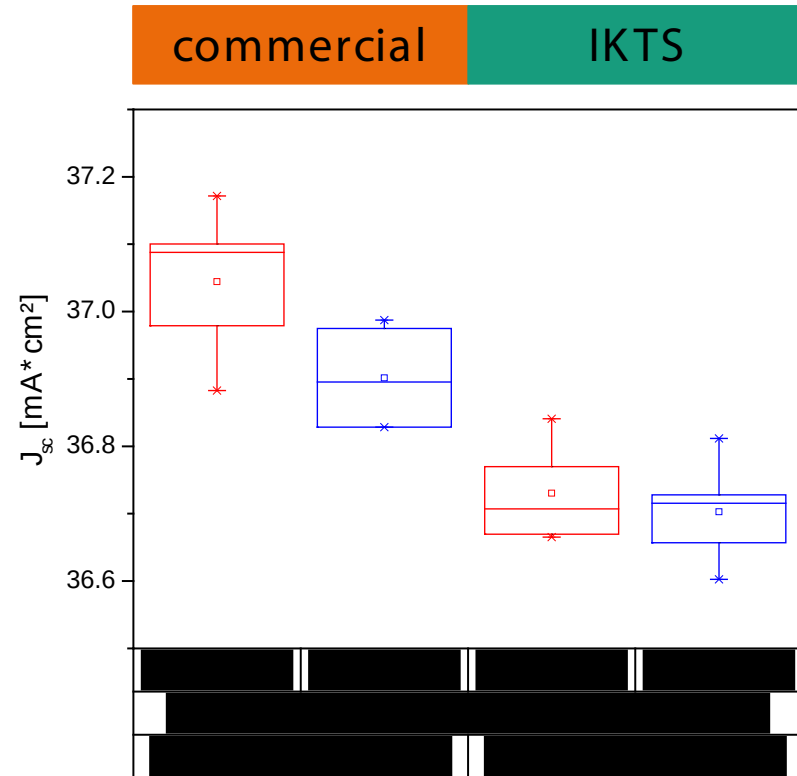
Experimental



OUTLINE

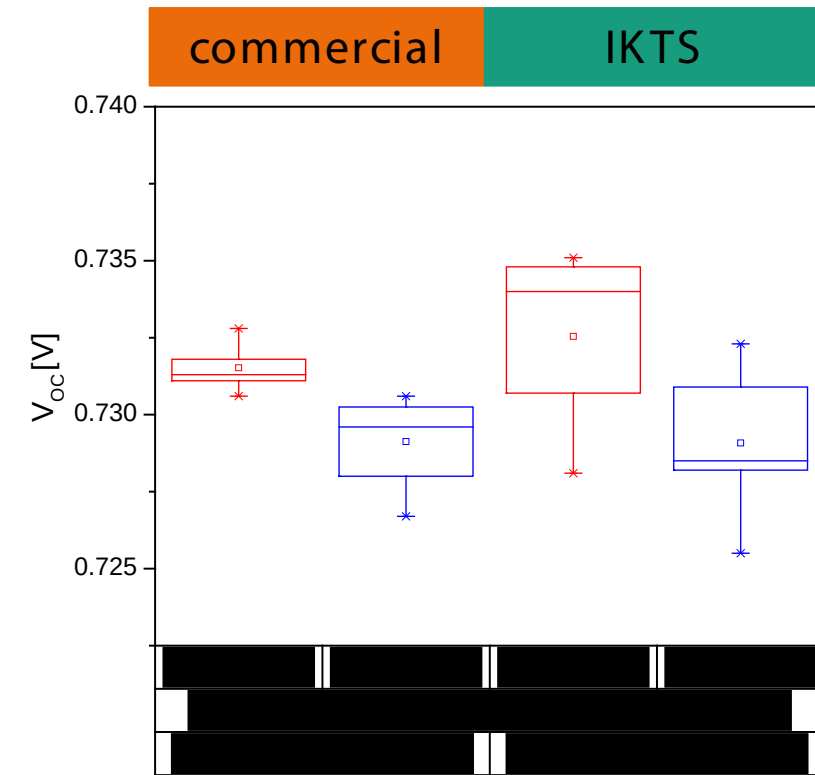
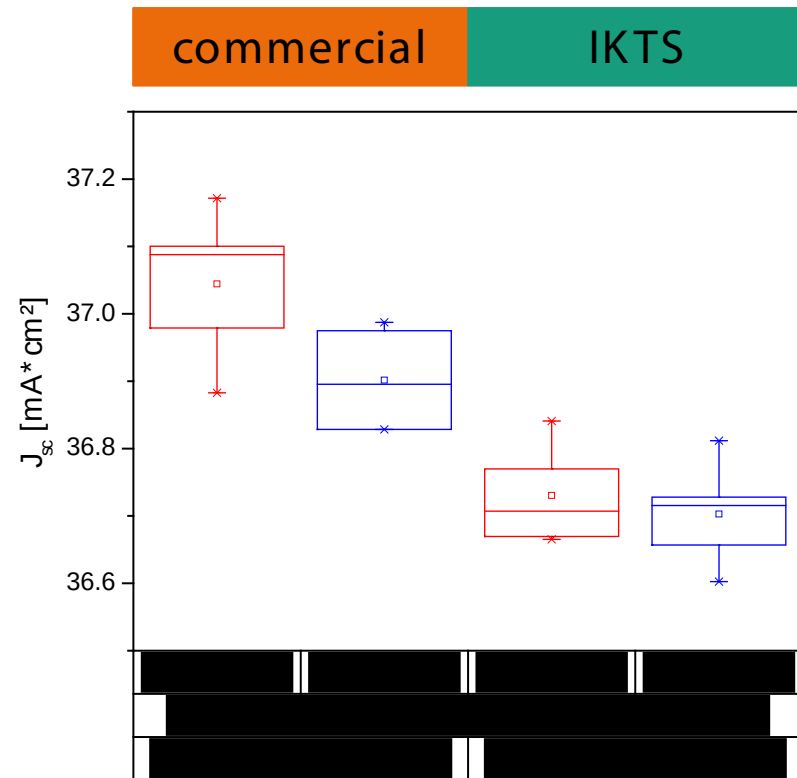
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Electrical performance



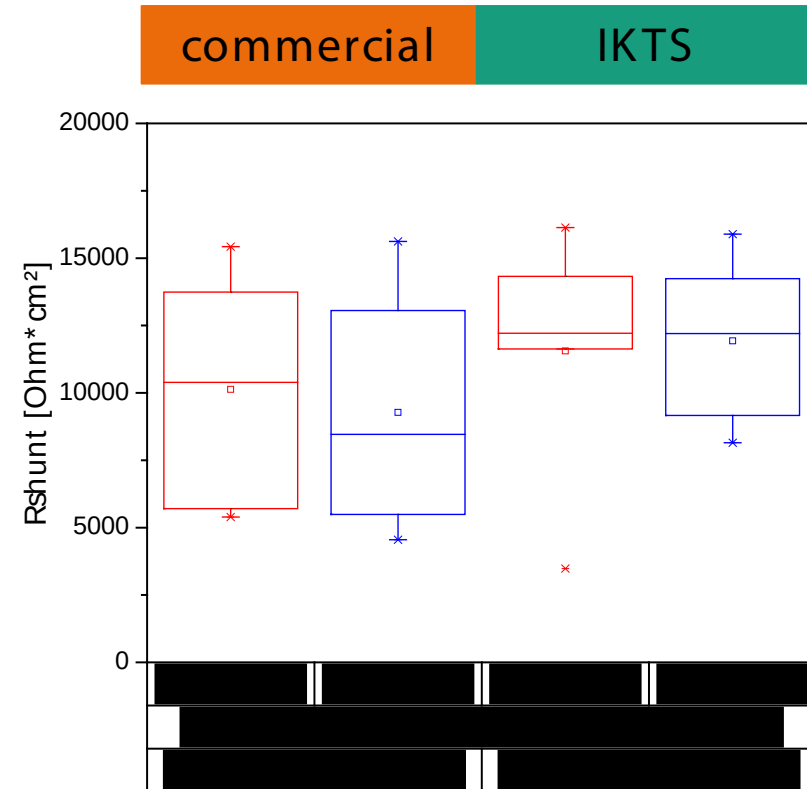
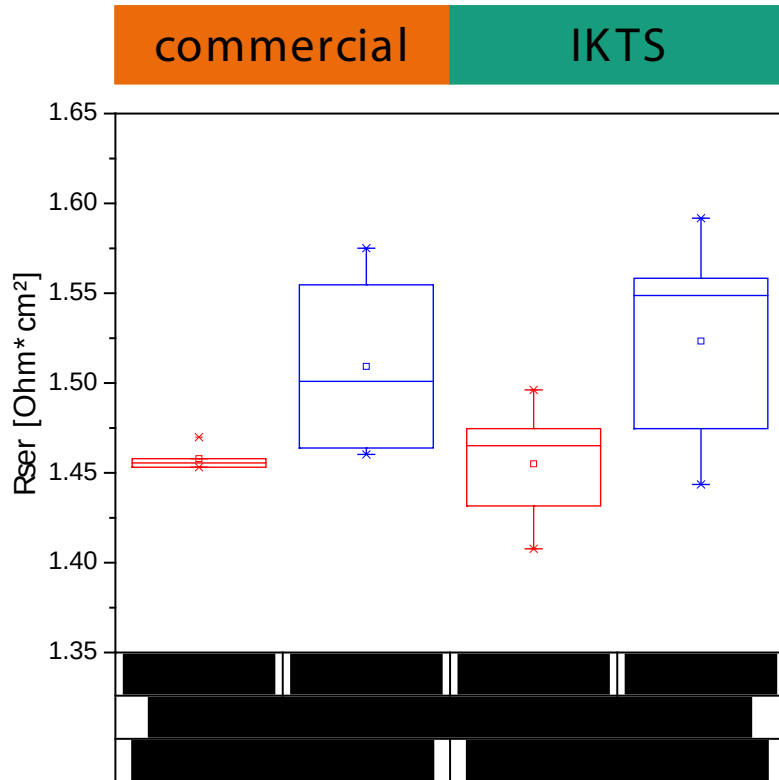
- IKTS pastes provide slightly lower J_{sc}
 - Optimizing paste rheology will increase J_{sc} due to optimized finger narrowing and decreasing shading

Electrical performance



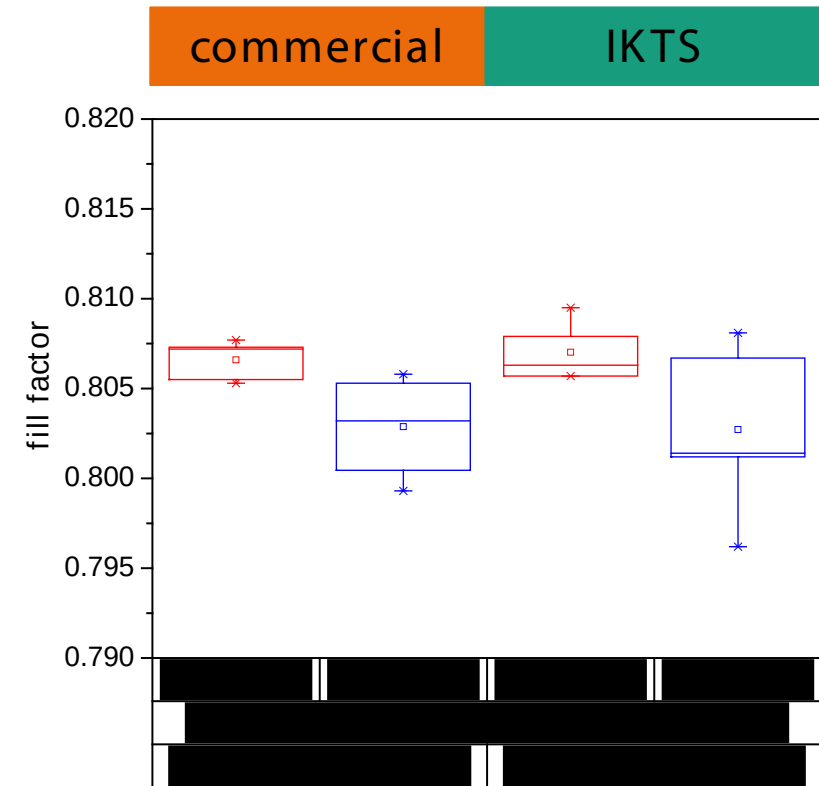
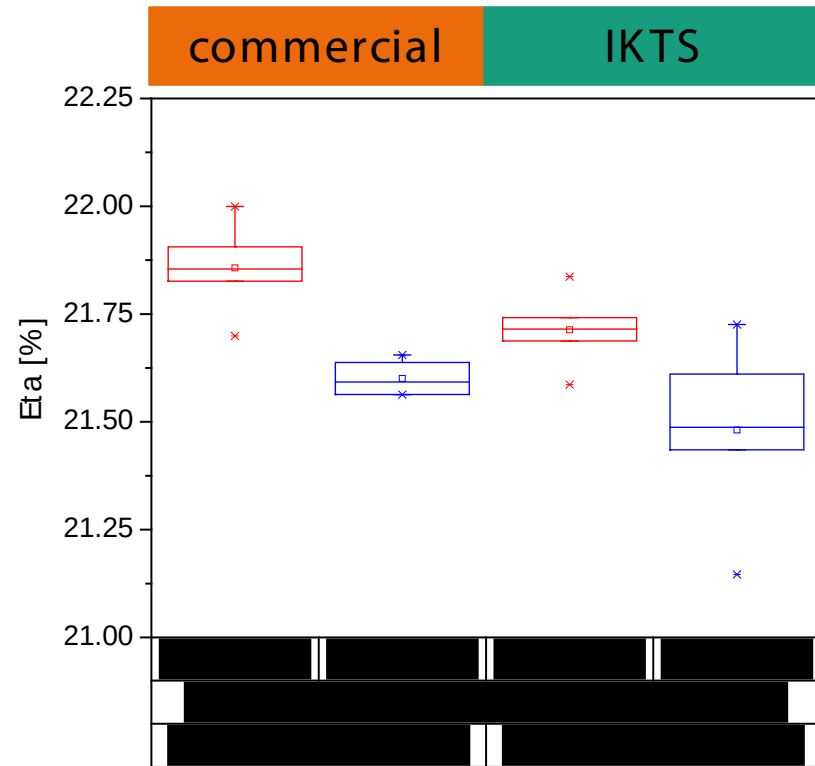
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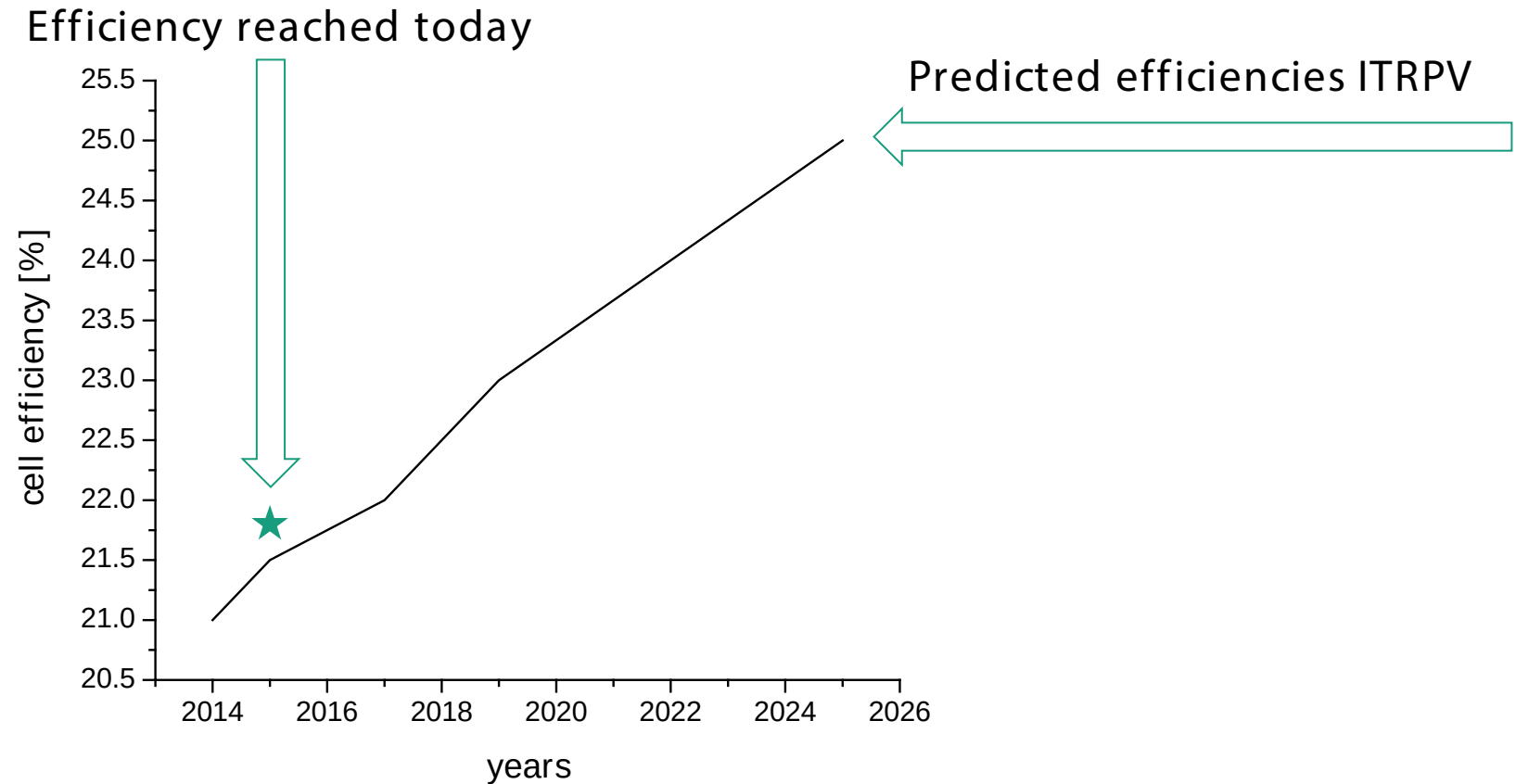
- Series resistances comparable for both pastes
- Infrared curing provides lower series resistances as well as a lower standard deviation
- Optimized heat transfer due to coupling of IR radiation

Electrical performance

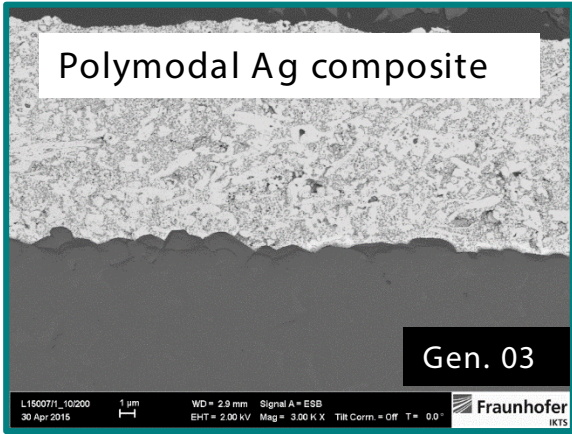
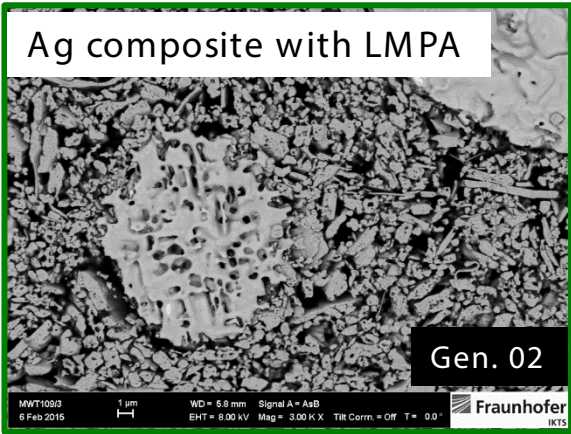
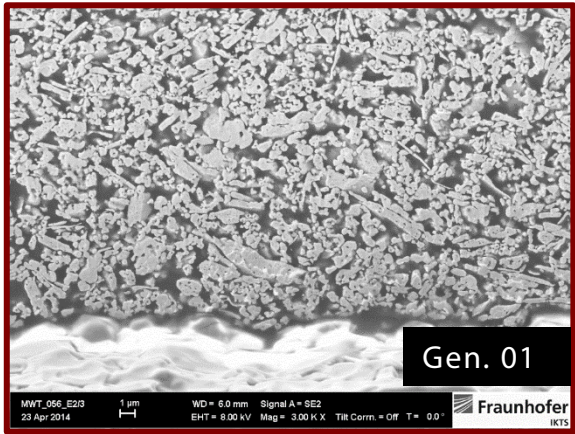
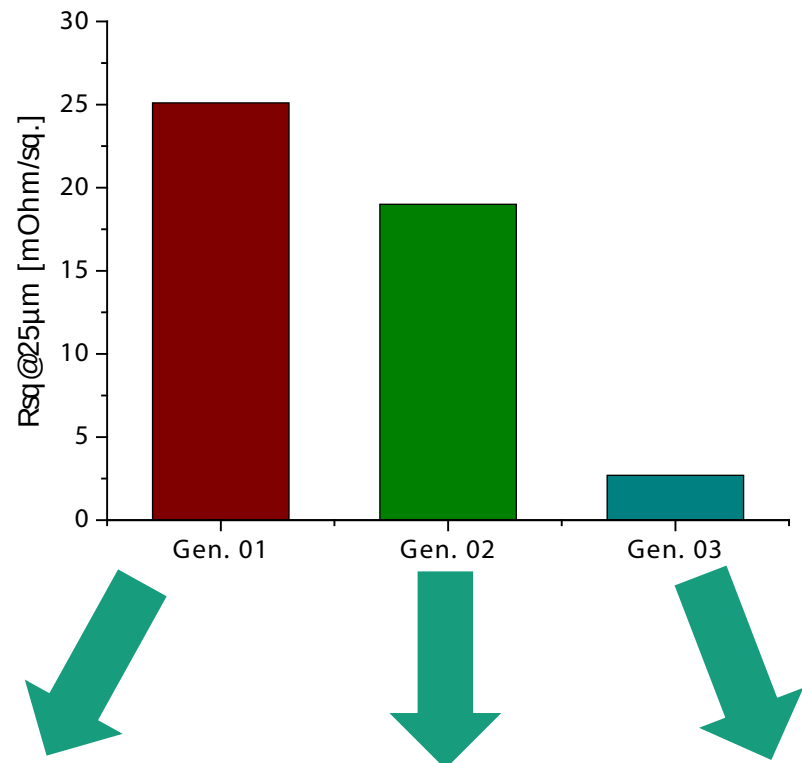


- Efficiency level higher than 21.5 %
 - CC commercial paste 22 % using IR curing → benefit against convection of 0.25 %
 - CC IKTS paste 21.8 % using IR curing → benefit against convection of 0.1 %
- Fill factor constant higher than 80 %

Presence and future of crystalline silicon solar cell

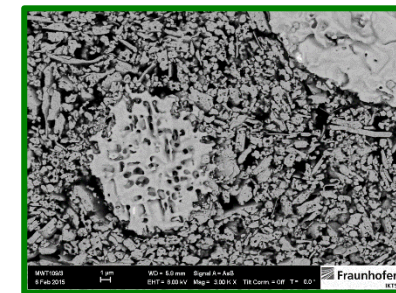
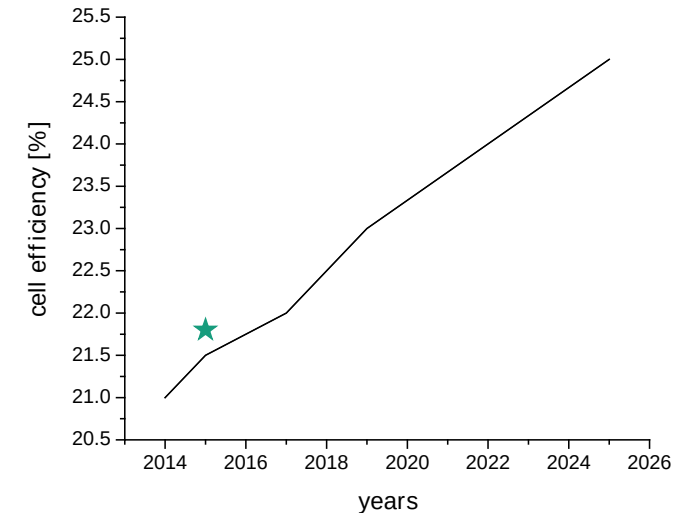


Performance forecast



Summary

- 1st generation IKTS paste curable at 200°C for SHJ solar cells is introduced
 - IR curing leads to better electrical performance of the reference paste as well as the own development, obviously due to improved microstructure formation
 - Electrical performance on cell level is comparable to industrial standard
 - Handling, storage and therewith processing of IKTS paste is much more easier than the commercial reference
- Further improvement announced with next generations:
 - low melting point alloys with reduced silver amount
 - polymodal silver powders for minimal finger resistances



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...and you for your attention!

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